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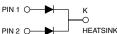
Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.45$ V at $I_F = 5$ A



www.vishay.com

V40D120C



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 20 A			
V _{RRM}	120 V			
I _{FSM}	250 A			
V_F at I_F = 20 A (T_A = 125 °C)	0.64 V			
TJ max.	150 °C			
Package	TO-263AC (SMPD)			
Diode variations	Dual common cathode			

FEATURES

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- AEC-Q101 qualified
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-263AC (SMPD)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	V40D120C	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	120	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	40		
	per diode		20	- A	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I _{FSM}	250	A	
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	- 40 to + 150	°C	



FREE

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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F (1)	0.51	-	V	
	I _F = 10 A			0.63	-		
	I _F = 20 A			0.78	0.89		
	$I_F = 5 A$	T _A = 125 °C		0.45	-		
	I _F = 10 A			0.55	-		
	I _F = 20 A			0.64	0.71		
Reverse current at rated V_R per diode	V _R = 90 V	T _A = 25 °C	I _R (2)	11	-	μA	
		T _A = 125 °C		9.4	-	mA	
	V _B = 120 V	T _A = 25 °C		-	500	μA	
	$v_{\rm R} = 120 V$	T _A = 125 °C		23	70	mA	

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 5 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER		SYMBOL	V40D120C	UNIT
Typical thermal resistance	per diode	- R _{θJC}	1.9	
	per device		1.0	°C/W
	per device	R _{0JA} ⁽¹⁾⁽²⁾	45	

Notes

⁽¹⁾ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{0JA}$

⁽²⁾ Free air, without heatsink

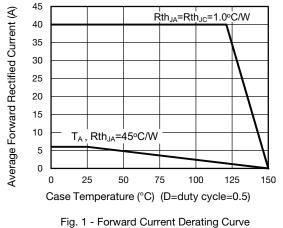
ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
SMPD	V40D120C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel	
SMPD	V40D120CHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel	

Note

(1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)



Average Power Loss (W) 2 0 8 12 0 4 Average Forward Current (A)

18

16

14

12

10

8

6

4

Fig. 2 - Forward Power Loss Characteristics Per Diode

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24

D = 0.8

16

1.0

D = 0.5

D = 0.3

D = 0.2

D = 0.1

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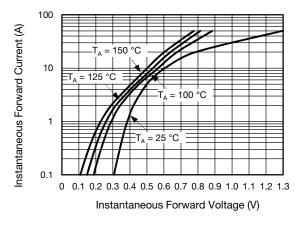


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

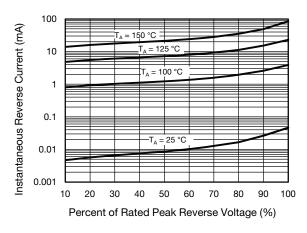


Fig. 4 - Typical Reverse Characteristics Per Diode

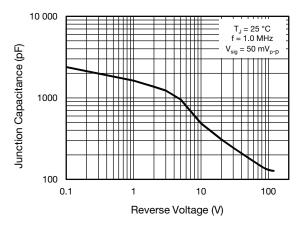


Fig. 5 - Typical Junction Capacitance Per Diode

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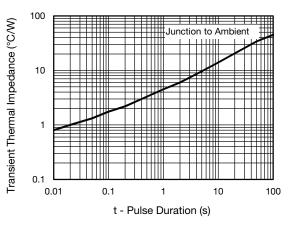


Fig. 6 - Typical Transient Thermal Impedance Per Device

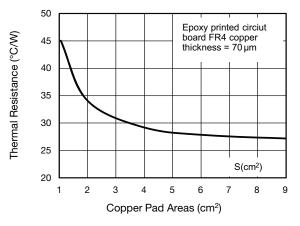


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

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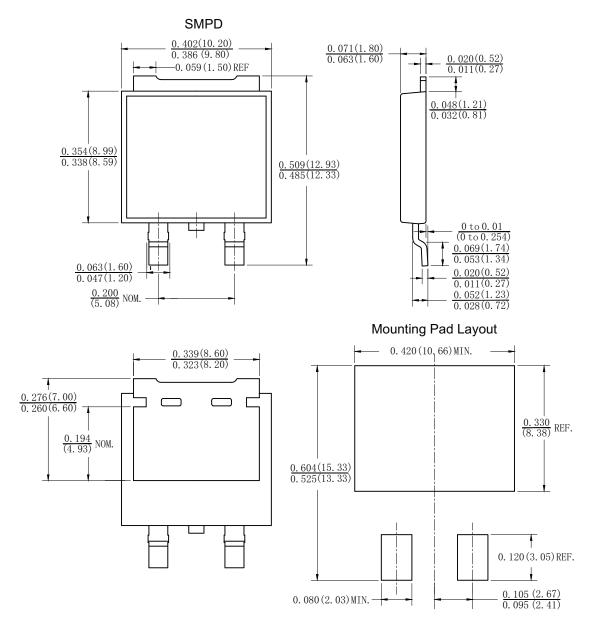
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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